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Facsimile Cover Sheet

Date:	November 26, 2003
To:	US Patent & Trademark Office Fax: 703-746-9195 Tel: 703-308-1202
From:	David E. Steuber Tel: 408/982-8200 ext. 1 Fax: 408/982-8210
Pages	4 (excluding cover sheet)

First Inventor:	Mohamed N. Darwish
Title:	Trench MOSFET Having Implanted Drain-Drift Region And Process For Manufacturing The Same
Serial No.:	10/650,513
Examiner:	Unknown

Enclosed for filing in the above-identified application are the following:
Transmittal Form (1 page);
Filing Receipt (with corrections shown) (1 page); and
Replacement Application Data Sheet (2 pages).

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PTO/SB/21 (08-00)

Approved for use through 10/31/02, OMB 0651-0031

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TRANSMITTAL
FORM

(to be used for all correspondence after initial filing)

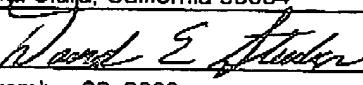
Total Number Of Pages In This Submission	4	Attorney Docket No.	SCX010-5D US
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ENCLOSURES (check all that apply)

<input type="checkbox"/> Fee Transmittal Form (1 page in duplicate)	<input type="checkbox"/> Assignment Papers (for an Application)	<input type="checkbox"/> After Allowance Communication to Group
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<input type="checkbox"/> Extension of Time Request (1 page in duplicate)	<input type="checkbox"/> Power of Attorney, Revocation of Previous Powers; And Statement Under 37 CFR 3.73(b)	Other Enclosure(s) (please identify below): <input checked="" type="checkbox"/> Marked-up Copy of Filing Receipt showing correction; (1 page); and Supplemental Application Data Sheet (2 pages).
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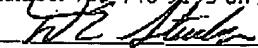
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SIGNATURE OF APPLICANT, ATTORNEY OR AGENT

Firm or Individual Name	Omkar K. Suryadevara (Reg. No. 36,320) Silicon Valley Patent Group LLP 2350 Mission College Boulevard, Suite 360 Santa Clara, California 95054
Signature	
Date	November 26, 2003

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11/26/03

Attorney for Applicant(s)

Date of Signature



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APPL NO.	FILING OR 371 (C) DATE	ART UNIT	FL FEE REC'D	ATTY.DOCKET NO	DRAWINGS	TOT CLMS	IND CLMS
10/650,513	08/27/2003	2812	750	SCX010-5D US	18	11	2

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CONFIRMATION NO. 5781
FILING RECEIPT

 "OC000000011306279"

Date Mailed: 11/19/2003

Receipt is acknowledged of this regular Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Office of Initial Patent Examination's Filing Receipt Corrections, facsimile number 703-746-9195. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

Applicant(s)

Mohamed N. Darwish, Campbell, CA;

Assignment For Published Patent Application

Siliconix Incorporated, Campbell, CA;

*Santa Clara***Domestic Priority data as claimed by applicant**

This application is a DIV of 10/317,568 12/12/2002
 which is a CIP of 09/898,652 07/03/2001 PAT 6,569,738

Foreign Applications**If Required, Foreign Filing License Granted: 11/19/2003****Projected Publication Date: 02/26/2004****Non-Publication Request: No****Early Publication Request: No****Title**

Trench MOSFET having implanted drain-drift region and process for manufacturing the same